

# 1-Mbit (64 K × 16) Static RAM

#### **Features**

- Temperature ranges
  - □ Automotive-A: -40 °C to 85 °C
  - □ Automotive-E: -40 °C to 125 °C
- Pin and function compatible with CY7C1021CV33
- High speed
  - $\Box$  t<sub>AA</sub> = 10 ns (Automotive-A)
  - $\Box$  t<sub>AA</sub> = 12 ns (Automotive-E)
- CMOS for optimum speed and power
- Low active power: 325 mW (max)
- Automatic power down when deselected
- Independent control of upper and lower bits
- Available in Pb-free and non Pb-free 44-pin 400 Mil SOJ, 44-pin TSOP II, and 48-ball FBGA packages

#### **Functional Description**

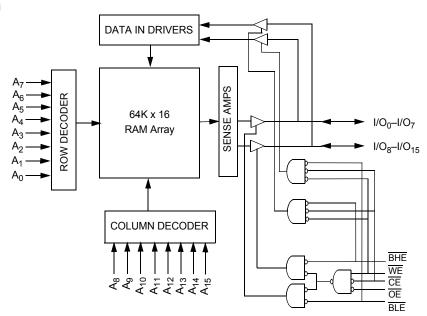
The CY7C1021CV33 is a high performance CMOS static RAM organized as 65,536 words by 16 bits. This device has an automatic power down feature that significantly reduces power consumption when deselected.

Writing to the device is accomplished by taking Chip Enable  $(\overline{CE})$  and Write Enable  $(\overline{WE})$  inputs LOW. If Byte Low Enable  $(\overline{BLE})$  is LOW, then data from I/O pins  $(I/O_1$  through  $I/O_8)$ , is written into the location specified on the address pins  $(A_0$  through  $A_{15})$ . If Byte High Enable  $(\overline{BHE})$  is LOW, then data from I/O pins  $(I/O_9$  through  $I/O_{16})$  is written into the location specified on the address pins  $(A_0$  through  $A_{15})$ .

Reading from the device is accomplished by taking Chip Enable  $(\overline{\text{CE}})$  and Output Enable  $(\overline{\text{OE}})$  LOW while forcing the Write Enable  $(\overline{\text{WE}})$  HIGH. If Byte Low Enable  $(\overline{\text{BLE}})$  is LOW, then data from the memory location specified by the address pins appear on I/O<sub>1</sub> to I/O<sub>8</sub>. If Byte High Enable  $(\overline{\text{BHE}})$  is LOW, then data from memory appears on I/O<sub>9</sub> to I/O<sub>16</sub>. For more information, see the Truth Table on page 10 for a complete description of Read and Write modes.

The input and output pins (I/O $_1$  through I/O $_{16}$ ) are placed in a high impedance state when the device is deselected (CE HIGH), the outputs are disabled (OE HIGH), the BHE and BLE are disabled (BHE, BLE HIGH), or during a write operation (CE LOW and WE LOW).

#### **Logic Block Diagram**



## CY7C1021CV33



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#### **Selection Guide**

| Description                  | Description  |    |    |    |  |  |
|------------------------------|--------------|----|----|----|--|--|
| Maximum Access Time          |              | 10 | 12 | ns |  |  |
| Maximum Operating Current    | Automotive-A | 90 | _  | mA |  |  |
|                              | Automotive-E | _  | 90 | mA |  |  |
| Maximum CMOS Standby Current | Automotive-A | 5  | _  | mA |  |  |
|                              | Automotive-E | _  | 10 | mA |  |  |

## **Pin Configuration**

Figure 1. 44-pin SOJ/TSOP II [1]

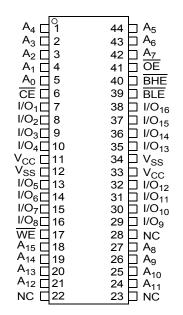
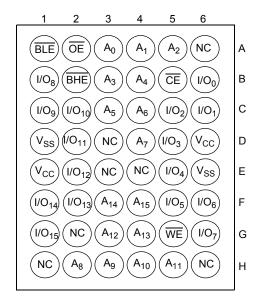


Figure 2. 48-ball FBGA Pinout [1]



#### Note

<sup>1.</sup> NC pins are not connected on the die.



## **Pin Definitions**

| Pin Name   | SOJ, TSOP<br>Pin Number      | BGA Pin<br>Number  | I/O Type            | Description   |
|--|------------------------------|--|---------------------|---|
| A <sub>0</sub> -A <sub>15</sub>                    | 1–5, 18–21,<br>24–27, 42–44  | A3, A4, A5, B3,<br>B4, C3, C4,<br>D4, H2, H3,<br>H4, H5, G3,<br>G4, F3, F4 | Input               | Address Inputs. Used to select one of the address locations.  |
| I/O <sub>1</sub> –I/O <sub>16</sub> <sup>[2]</sup> | 7–10, 13–16,<br>29–32, 35–38 | B6, C6, C5,<br>D5, E5, F5, F6,<br>G6, B1, C1,<br>C2, D2, E2,<br>F2, F1, G1 | Input or Output     | Bidirectional Data I/O lines. Used as input or output lines depending on operation.   |
| NC   | 22, 23, 28                   | A6, D3, E3,<br>E4, G2, H1, H6  | No Connect          | No Connects. Not connected to the die.  |
| WE   | 17                           | G5   | Input or<br>Control | Write Enable Input, Active LOW. When selected LOW, a write is conducted. When deselected HIGH, a read is conducted.   |
| CE   | 6                            | B5   | Input or<br>Control | Chip Enable Input, Active LOW. When LOW, selects the chip. When HIGH, deselects the chip.   |
| BHE, BLE   | 40, 39                       | B2, A1   | Input or<br>Control | Byte Write Select Inputs, Active LOW. $\overline{\rm BHE}$ controls I/O <sub>16</sub> – I/O <sub>9</sub> , BLE controls I/O <sub>8</sub> – I/O <sub>1</sub> .   |
| ŌĒ   | 41                           | A2   | Input or<br>Control | <b>Output Enable, Active LOW.</b> Controls the direction of the I/O pins. When LOW, the I/O pins are allowed to behave as outputs. When deasserted HIGH, the I/O pins are tristated and act as input data pins. |
| V <sub>SS</sub>                                    | 12, 34                       | D1, E6   | Ground              | Ground for the Device. Connected to ground of the system.   |
| V <sub>CC</sub>                                    | 11, 33                       | D6, E1   | Power Supply        | Power Supply Inputs to the Device.  |

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Note 2. I/O1-I/O16 for SOJ/TSOP and I/O0-I/O15 for BGA packages.



## **Maximum Ratings**

| DC Input Voltage [3]                                | 0.5 V to V <sub>CC</sub> + 0.5 V |
|---|----------------------------------|
| Current into Outputs (LOW)                          | 20 mA                            |
| Static Discharge Voltage (MIL-STD-883, Method 3015) | > 2001 V                         |
| Latch Up Current                                    | > 200 mA                         |

#### **Operating Range**

| Range        | Ambient Temperature (T <sub>A</sub> ) | V <sub>CC</sub> |
|--------------|---------------------------------------|-----------------|
| Automotive-A | –40 °C to +85 °C                      | $3.3~V\pm10\%$  |
| Automotive-E | –40 °C to +125 °C                     |                 |

#### **Electrical Characteristics**

Over the Operating Range

| Parameter        | Description                      | Test Conditions  |              | -10        |                | -12  |                | Unit  |
|------------------|----------------------------------|--|--------------|------------|----------------|------|----------------|-------|
| Parameter        | Description                      |  |              | Min        | Max            | Min  | Max            | Oille |
| V <sub>OH</sub>  | Output HIGH Voltage              | V <sub>CC</sub> = Min, I <sub>OH</sub> = -4  | 4.0 mA       | 2.4        | _              | 2.4  | _              | V     |
| $V_{OL}$         | Output LOW Voltage               | $V_{CC}$ = Min, $I_{OL}$ = 8.  | 0 mA         | -          | 0.4            | _    | 0.4            | V     |
| V <sub>IH</sub>  | Input HIGH Voltage               |  |              | 2.0        | $V_{CC} + 0.3$ | 2.0  | $V_{CC} + 0.3$ | V     |
| $V_{IL}$         | Input LOW Voltage[3]             |  |              | -0.3       | 0.8            | -0.3 | 0.8            | V     |
| I <sub>IX</sub>  | Input Leakage Current            | $GND \le V_I \le V_{CC}$   | Automotive-A | <b>–</b> 1 | +1             | _    | _              | μΑ    |
|                  |                                  |  | Automotive-E | _          | _              | -12  | +12            |       |
| I/O <sub>Z</sub> | Output Leakage Current           |  | Automotive-A | -1         | +1             | _    | _              | μΑ    |
|                  |                                  | Output disabled  | Automotive-E | _          | _              | -12  | +12            |       |
| I <sub>CC</sub>  | V <sub>CC</sub> Operating Supply | V <sub>CC</sub> = Max,   | Automotive-A | _          | 90             | _    | _              | mA    |
|                  | Current                          | $I_{OUT} = 0 \text{ mA},$<br>$f = f_{MAX} = 1/t_{RC}$  | Automotive-E | _          | _              | _    | 90             |       |
| I <sub>SB1</sub> | Automatic CE Power               | Max V <sub>CC</sub> ,  | Automotive-A | _          | 15             | _    | _              | mA    |
|                  | Down Current —TTL<br>Inputs      | $CE \ge V_{IH}$<br>$V_{IN} \ge V_{IH}$ or<br>$V_{IN} \le V_{IL}$ , $f = f_{MAX}$                       | Automotive-E | -          | _              | _    | 20             |       |
| I <sub>SB2</sub> | Automatic CE Power               | Max V <sub>CC</sub> ,  | Automotive-A | _          | 5              | _    | _              | mA    |
|                  | Down Current — CMOS Inputs       | $CE \ge V_{CC} - 0.3 \text{ V}, V_{IN} \ge V_{CC} - 0.3 \text{ V}, or V_{IN} \le 0.3 \text{ V}, f = 0$ | Automotive-E | -          | _              | -    | 10             |       |

#### Note

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<sup>3.</sup>  $V_{IL}$  (min) = -2.0 V and  $V_{IH}$ (max) =  $V_{CC}$  + 0.5 V for pulse durations of less than 20 ns.



## Capacitance

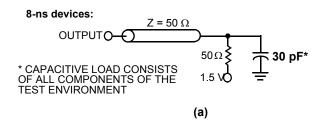
| Parameter [4]    | Description        | Test Conditions  | Max | Unit |
|------------------|--------------------|--|-----|------|
| C <sub>IN</sub>  | Input Capacitance  | $T_A = 25 ^{\circ}\text{C}$ , $f = 1 \text{MHz}$ , $V_{CC} = 3.3 \text{V}$ | 8   | pF   |
| C <sub>OUT</sub> | Output Capacitance |  | 8   | pF   |

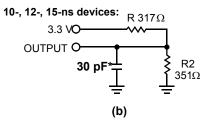
#### **Thermal Resistance**

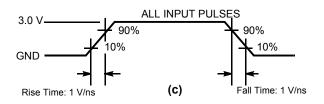
| Ī | Parameter [4]     | Description          | Test Conditions   | 44-pin SOJ | 44-pin TSOP II | 48-ball FBGA | Unit |
|---|-------------------|----------------------|---|------------|----------------|--------------|------|
| Ī | $\Theta_{JA}$     | ,                    | Test conditions follow standard test methods and procedures for | 65.06      | 76.92          | 95.32        | °C/W |
|   | $\Theta_{\sf JC}$ | i i nemai Resisiance | measuring thermal impedance,<br>per EIA/JESD51                  | 34.21      | 15.86          | 10.68        | °C/W |

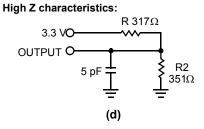
#### **AC Test Loads and Waveforms**

Figure 3. AC Test Loads and Waveforms [5]









#### Notes

- Tested initially and after any design or process changes that may affect these parameters.
   AC characteristics (except High Z) for all 8-ns parts are tested using the load conditions shown in Figure 3 (a). All other speeds are tested using the Thevenin load shown in Figure 3 (b). High Z characteristics are tested for all speeds using the test load shown in Figure 3 (d).



### **Switching Characteristics**

Over the Operating Range

|                                   |   | -        | 10  | _'  |     |      |
|-----------------------------------|---|----------|-----|-----|-----|------|
| Parameter [6]                     | Description                                   | Min      | Max | Min | Max | Unit |
| Read Cycle                        |   | •        | •   | •   | •   |      |
| t <sub>power</sub> <sup>[7]</sup> | V <sub>CC</sub> (Typical) to the First Access | 100      | _   | 100 | _   | μS   |
| t <sub>RC</sub>                   | Read Cycle Time                               | 10       | _   | 12  | _   | ns   |
| t <sub>AA</sub>                   | Address to Data Valid                         | _        | 10  | _   | 12  | ns   |
| t <sub>OHA</sub>                  | Data Hold from Address Change                 | 3        | _   | 3   | _   | ns   |
| t <sub>ACE</sub>                  | CE LOW to Data Valid                          | _        | 10  | _   | 12  | ns   |
| t <sub>DOE</sub>                  | OE LOW to Data Valid                          | _        | 5   | _   | 6   | ns   |
| t <sub>LZOE</sub>                 | OE LOW to Low Z <sup>[8]</sup>                | 0        | _   | 0   | _   | ns   |
| t <sub>HZOE</sub>                 | OE HIGH to High Z <sup>[8, 9]</sup>           | _        | 5   | _   | 6   | ns   |
| t <sub>LZCE</sub>                 | CE LOW to Low Z <sup>[8]</sup>                | 3        | _   | 3   | _   | ns   |
| t <sub>HZCE</sub>                 | CE HIGH to High Z <sup>[8, 9]</sup>           | _        | 5   | _   | 6   | ns   |
| t <sub>PU</sub> <sup>[10]</sup>   | CE LOW to Power Up                            | 0        | _   | 0   | _   | ns   |
| t <sub>PD</sub> <sup>[10]</sup>   | CE HIGH to Power Down                         | _        | 10  | _   | 12  | ns   |
| t <sub>DBE</sub>                  | Byte Enable to Data Valid                     | _        | 5   | _   | 6   | ns   |
| t <sub>LZBE</sub>                 | Byte Enable to Low Z                          | 0        | _   | 0   | _   | ns   |
| t <sub>HZBE</sub>                 | Byte Disable to High Z                        | _        | 5   | _   | 6   | ns   |
| Write Cycle <sup>[1]</sup>        | ij  | <u>.</u> |     |     |     | •    |
| t <sub>WC</sub>                   | Write Cycle Time                              | 10       | _   | 12  | _   | ns   |
| t <sub>SCE</sub>                  | CE LOW to Write End                           | 8        | _   | 9   | _   | ns   |
| t <sub>AW</sub>                   | Address Setup to Write End                    | 8        | _   | 9   | _   | ns   |
| t <sub>HA</sub>                   | Address Hold from Write End                   | 0        | _   | 0   | _   | ns   |
| t <sub>SA</sub>                   | Address Setup to Write Start                  | 0        | _   | 0   | _   | ns   |
| t <sub>PWE</sub>                  | WE Pulse Width                                | 7        | _   | 8   | _   | ns   |
| t <sub>SD</sub>                   | Data Setup to Write End                       | 5        | _   | 6   | _   | ns   |
| t <sub>HD</sub>                   | Data Hold from Write End                      | 0        | _   | 0   | _   | ns   |
| t <sub>LZWE</sub>                 | WE HIGH to Low Z <sup>[8]</sup>               | 3        | _   | 3   | _   | ns   |
| t <sub>HZWE</sub>                 | WE LOW to High Z <sup>[8, 9]</sup>            | -        | 5   | _   | 6   | ns   |
| t <sub>BW</sub>                   | Byte Enable to End of Write                   | 7        | -   | 8   | _   | ns   |

- Notes

  6. Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V.

  7. t<sub>POWER</sub> gives the minimum amount of time that the power supply is at typical V<sub>CC</sub> values until the first memory access is performed.

  8. At any temperature and voltage condition, t<sub>HZCE</sub> is less than t<sub>LZCE</sub>, t<sub>HZOE</sub> is less than t<sub>LZCE</sub>, and t<sub>HZWE</sub> for any given device.

  9. t<sub>HZOE</sub>, t<sub>HZBE</sub>, t<sub>HZCE</sub>, and t<sub>HZWE</sub> are specified with a load capacitance of 5 pF as in part (d) of Figure 3 on page 6. Transition is measured ±500 mV from steady state voltage.

  10. This parameter is guaranteed by design and is not tested.

  11. The internal write time of the memory is defined by the overlap of CE LOW, WE LOW, and BHE/BLE LOW. CE, WE, and BHE/BLE is LOW to initiate a write. The transition of these signals terminate the write. The input data setup and hold timing is referenced to the leading edge of the signal that terminates the write.

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## **Switching Waveforms**

Figure 4. Read Cycle No. 1 (Address Transition Controlled)[12, 13]

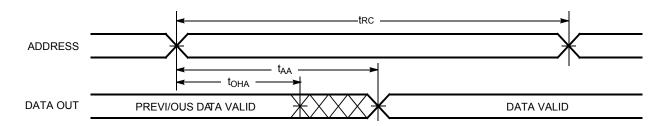
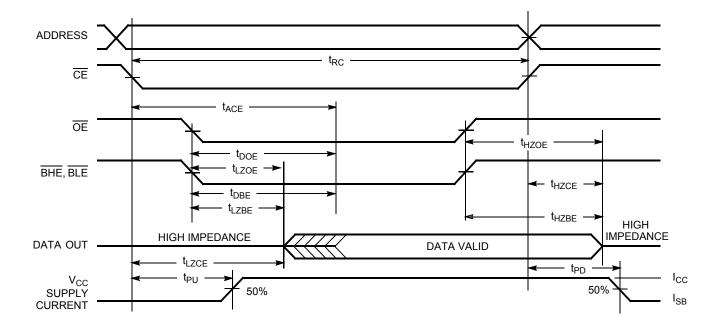


Figure 5. Read Cycle No. 2 (OE Controlled)[13, 14]



<sup>12. &</sup>lt;u>Device</u> is continuously selected. <u>OE</u>, <u>CE</u>, <u>BHE</u>, and/or <u>BLE</u> = V<sub>IL</sub>.

13. <u>WE</u> is HIGH for read cycle.

14. Address valid prior to or coincident with <u>CE</u> transition LOW.



## Switching Waveforms (continued)

Figure 6. Write Cycle No. 1 (CE Controlled)[15, 16]

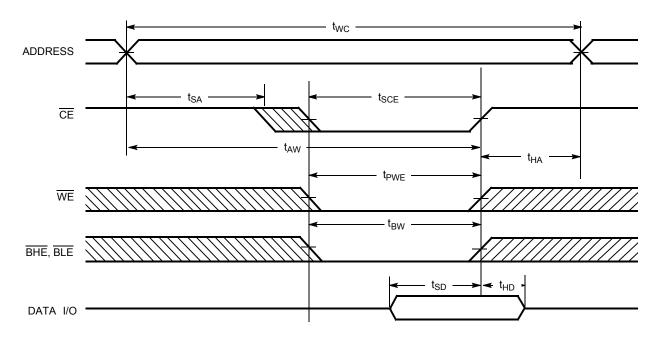
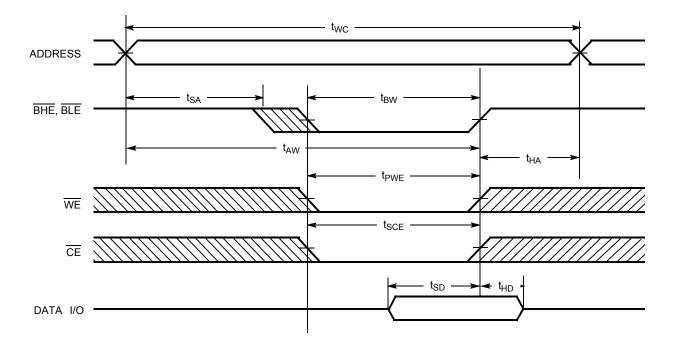


Figure 7. Write Cycle No. 2 (BLE or BHE Controlled)



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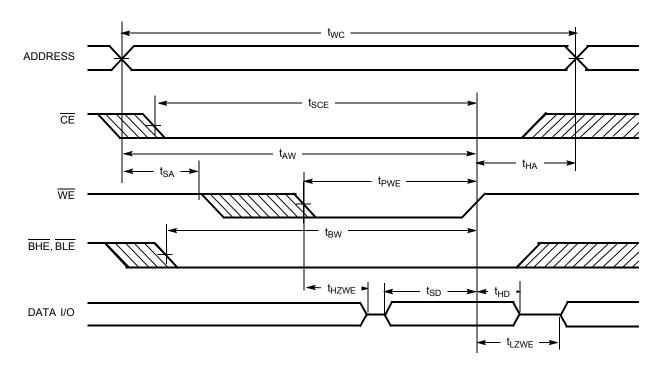
<sup>15.</sup> Data I/O is high impedance if OE, BHE, and/or BLE = V<sub>IH</sub>.

16. If CE goes HIGH simultaneously with WE going HIGH, the output remains in a high impedance state.



## Switching Waveforms (continued)

Figure 8. Write Cycle No. 3 (WE Controlled, LOW)



### **Truth Table**

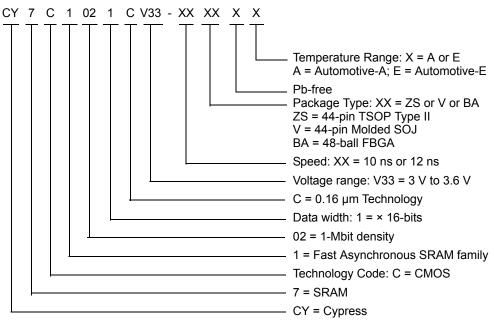
| CE | OE | WE | BLE | BHE | I/O <sub>1</sub> – I/O <sub>8</sub> | I/O <sub>9</sub> – I/O <sub>16</sub> | Mode                       | Power                      |
|----|----|----|-----|-----|-------------------------------------|--------------------------------------|----------------------------|----------------------------|
| Н  | X  | Х  | X   | Х   | High Z                              | High Z                               | Power Down                 | Standby (I <sub>SB</sub> ) |
| L  | L  | Н  | L   | L   | Data Out                            | Data Out                             | Read – All Bits            | Active (I <sub>CC</sub> )  |
|    |    |    | L   | Н   | Data Out                            | High Z                               | Read – Lower Bits Only     | Active (I <sub>CC</sub> )  |
|    |    |    | Ι   | L   | High Z                              | Data Out                             | Read – Upper Bits Only     | Active (I <sub>CC</sub> )  |
| L  | X  | Г  | L   | L   | Data In                             | Data In                              | Write – All Bits           | Active (I <sub>CC</sub> )  |
|    |    |    | L   | Н   | Data In                             | High Z                               | Write – Lower Bits Only    | Active (I <sub>CC</sub> )  |
|    |    |    | Н   | L   | High Z                              | Data In                              | Write – Upper Bits Only    | Active (I <sub>CC</sub> )  |
| L  | Н  | Н  | Х   | Х   | High Z                              | High Z                               | Selected, Outputs Disabled | Active (I <sub>CC</sub> )  |
| L  | Х  | Х  | Н   | Н   | High Z                              | High Z                               | Selected, Outputs Disabled | Active (I <sub>CC</sub> )  |



## **Ordering Information**

| Speed (ns) | Ordering Code       | Package<br>Diagram | Package Type                          | Operating<br>Range |
|------------|---------------------|--------------------|---------------------------------------|--------------------|
| 10         | CY7C1021CV33-10ZSXA | 51-85087           | 44-pin TSOP Type II (Pb-free)         | Automotive-A       |
| 12         | CY7C1021CV33-12VXE  | 51-85082           | 44-pin (400-Mil) Molded SOJ (Pb-free) | Automotive-E       |
|            | CY7C1021CV33-12ZSXE | 51-85087           | 44-pin TSOP Type II (Pb-free)         | ]                  |
|            | CY7C1021CV33-12BAE  | 51-85096           | 48-ball FBGA                          |                    |

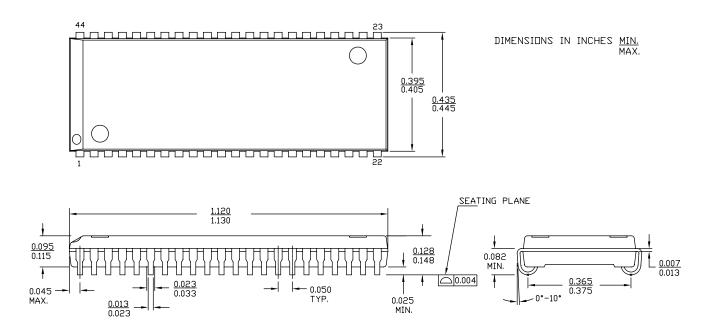
#### **Ordering Code Definitions**





## **Package Diagrams**

Figure 9. 44-pin SOJ (400 Mils) V44.4 Package Outline, 51-85082

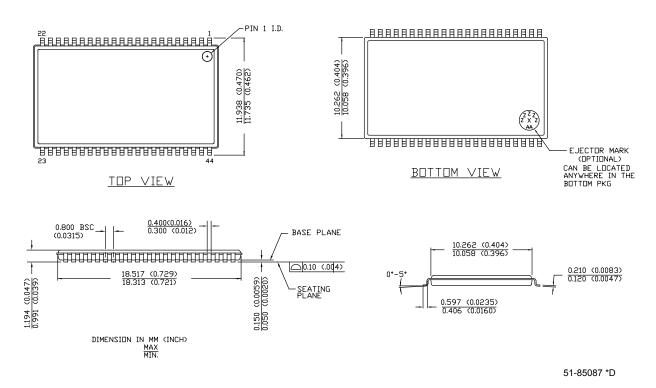


51-85082 \*D



## Package Diagrams (continued)

Figure 10. 44-pin TSOP Z44-II Package Outline, 51-85087



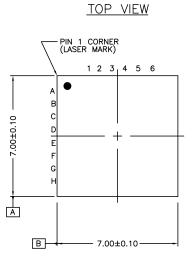
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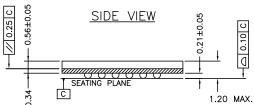
[+] Feedback

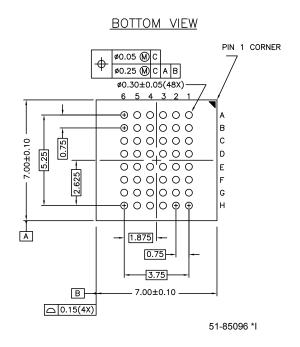


## Package Diagrams (continued)

Figure 11. 48-ball FBGA (7 × 7 × 1.2 mm) BA48 Package Outline, 51-85096









## **Acronyms**

| Acronym | Description                             |  |  |
|---------|---|--|--|
| BGA     | ball grid array                         |  |  |
| CE      | chip enable                             |  |  |
| CMOS    | complementary metal oxide semiconductor |  |  |
| FBGA    | fine-pitch ball grid array              |  |  |
| I/O     | input/output                            |  |  |
| OE      | output enable                           |  |  |
| SOJ     | small outline J-lead                    |  |  |
| SRAM    | static random access memory             |  |  |
| TQFP    | thin quad flat pack                     |  |  |
| TSOP    | thin small-outline package              |  |  |
| TTL     | transistor-transistor logic             |  |  |
| WE      | write enable                            |  |  |

## **Document Conventions**

#### **Units of Measure**

| Symbol | Unit of Measure |  |  |
|--------|-----------------|--|--|
| °C     | degree Celsius  |  |  |
| μΑ     | microampere     |  |  |
| μs     | microsecond     |  |  |
| mA     | milliampere     |  |  |
| mm     | millimeter      |  |  |
| mW     | milliwatt       |  |  |
| MHz    | megahertz       |  |  |
| ns     | nanosecond      |  |  |
| %      | percent         |  |  |
| pF     | picofarad       |  |  |
| V      | volt            |  |  |
| W      | watt            |  |  |



# **Document History Page**

| Document Title: CY7C1021CV33, 1-Mbit (64 K × 16) Static RAM Document Number: 38-05132 |         |                    |                 |  |  |
|---|---------|--------------------|-----------------|--|--|
| REV.  | ECN NO. | Submission<br>Date | Orig. of Change | Description of Change  |  |
| **  | 109472  | 12/06/01           | HGK             | New data sheet   |  |
| *A  | 115044  | 05/08/02           | HGK             | Ram7 version C4K x 16 Async Removed "Preliminary"  |  |
| *B  | 115808  | 06/25/02           | HGK             | I <sub>SB1</sub> and I <sub>CC</sub> values changed  |  |
| *C  | 120413  | 10/31/02           | DFP             | Updated BGA pin E4 to NC   |  |
| *D  | 238454  | See ECN            | RKF             | Added Automotive Specifications to datasheet Added Pb-free devices in the Ordering Information   |  |
| *E  | 334398  | See ECN            | SYT             | Added Pb-free on page 9 and 10   |  |
| *F  | 493565  | See ECN            | NXR             | Added Automotive-A operating range Corrected typo in the Pin Definition table Changed the description of I <sub>IX</sub> from Input Load Current to Input Leakage Current in DC Electrical Characteristics table Removed I <sub>OS</sub> parameter from DC Electrical Characteristics table Updated the ordering information table   |  |
| *G  | 563963  | See ECN            | VKN             | Added t <sub>POWER</sub> specification in the AC Switching Characteristics table Added footnote 8  |  |
| *H  | 1390863 | See ECN            | VKN /<br>AESA   | Corrected TSOP II package outline  |  |
| *   | 1891366 | See ECN            | VKN /<br>AESA   | Added -10ZSXA part in the Ordering Information table Updated Ordering Information Table  |  |
| *J  | 2880096 | 02/17/2010         | VKN /<br>AESA   | Added "CY7C1021CV33-10ZXI" part in the Ordering Information table Updated package diagrams.  |  |
| *K  | 2897691 | 03/23/2010         | RAME            | Updated Ordering Information Updated Package Diagrams  |  |
| *L  | 3089939 | 11/18/2010         | PRAS            | Removed inactive parts from Ordering Information.  |  |
| *M  | 3127893 | 01/04/2011         | HMLA            | Added Ordering Code Definitions. Added Acronyms and Units of Measure. Updated in new template.   |  |
| *N  | 3272897 | 06/07/2011         | HMLA            | Updated Features (Removed the information associated with speed bins and also the information associated with Commercial and Industrial parts.) Updated Functional Description (Removed "For best practice recommendations, refer to the Cypress application note AN1064, SRAN System Guidelines."). Updated Selection Guide (Removed the information associated with Commercial and Industrial parts.) Updated Operating Range (Removed the information associated with Commercial and Industrial parts.) Updated Electrical Characteristics (Removed the information associated with Commercial and Industrial parts.) Updated Package Diagrams. |  |
| *O  | 3400821 | 10/10/2011         | HMLA            | Updated Operating Range (Straddled both rows under V <sub>CC</sub> column so that the same condition is applicable for both Automotive-A and Automotive-E ranges) Updated Ordering Information (Removed the Note "The 44-pin TSOP package containing the Automotive grade device is designated as "ZS", while the same package containing the Commercial/Industrial grade device is "Z". below the Ordering Information table since Commercial/Industrial grade devices are not offered in this data sheet). Updated Package Diagrams.   |  |

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